ATTORNEY DOCKET NO. 040894-7171

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IN THE CLAIMS:

Please amend the claims to read as follows:

1 (Original): An oxinitride thermoelectric material, which has an element composition represented by the following formula (A):

$$Al_{z}Ga_{y}In_{x}M_{u}R_{v}O_{s}N_{t} \tag{A}$$

wherein M represents a transition element; R represents a rare earth element; $0 \le z \le 0.7, \ 0 \le y \le 0.7, \ 0.2 \le x \le 1.0, \ 0 \le u \le 0.7, \ 0 \le v \le 0.05, \ 0.9 \le s + t \le 1.7, \ and \ 0.4 \le s \le 1.2;$ and x+y+z=1, and

has an absolute value of a Seebeck coefficient of 40 $\mu V/K$ or more at a temperature of 100°C or more.

- 2 (Original): The oxinitride thermoelectric material according to claim 1, wherein the element composition has an electrical resistivity of $10^{-3} \Omega cm$ or less.
- 3 (Currently Amended): The oxinitride thermoelectric material according to claim 1 or 2, wherein M in formula (A) is at least one transition element selected from Ni, Fe, Co and Mn.
- 4 (Currently Amended): The oxinitride thermoelectric material according to claim 1 or 2, wherein R in formula (A) is at least one rare earth element selected from Gd, Sc, Sm, Tb and Dy.
- 5 (Currently Amended): The oxinitride thermoelectric material according to any one of claims claim 1 to 4, which comprises at least one having an amorphous structure.

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6 (Original): A nitride thermoelectric material which has an element composition represented by formula (B):

$$Al_zGa_vIn_xM_uR_vD_wN_m (B)$$

wherein M represents a transition element; R represents a rare earth element; D represents at least one element selected from elements of the Group IV or II; $0 \le z \le 0.7, \ 0 \le y \le 0.7, \ 0.2 \le x \le 1.0, \ 0 \le u \le 0.7, \ 0 \le v \le 0.05, \ 0 \le w \le 0.2, \ and \ 0.9 \le m \le 1.1;$ and x+y+z=1, and

has an absolute value of a Seebeck coefficient of 50 μ V/K or more at a temperature of 100°C or more, and an electrical resistivity of $10^{-3}~\Omega cm$ or less.

7 (Original): The nitride thermoelectric material according to claim 6, wherein M in formula (B) is at least transition element selected from Ni, Fe, Co and Mn.

8 (Original): The nitride thermoelectric material according to claim 6, wherein R in formula (B) is at least rare earth element selected from Gd, Sc, Sm and Tb.

9 (Original): The nitride thermoelectric material according to claim 6, wherein D in formula (B) is at least one element selected from Ge, Si, Mg and Zn.

10 (Currently Amended): The nitride thermoelectric material according to any one of claims claim 6 to 9, which comprises at least one having a wurtzite crystal structure.

11 (Currently Amended): The nitride thermoelectric material according to any one of claims claim 6 to 9, which comprises at least one having an amorphous structure.